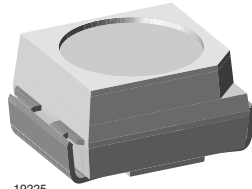


## Standard SMD LED PLCC-2



19225

### DESCRIPTION

This device has been designed to meet the increasing demand for AlInGaP technology.

The package of the VLMK31.. is the PLCC-2.

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

### PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD PLCC-2
- Product series: standard
- Angle of half intensity:  $\pm 60^\circ$

### FEATURES

- SMD LED with exceptional brightness
- Luminous intensity categorized
- Compatible with automatic placement equipment
- EIA and ICE standard package
- Compatible with IR reflow, vapor phase and wave solder processes according to CECC 00802 and J-STD-020C
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit  $I_{Vmax}/I_{Vmin} \leq 1.6$
- Lead (Pb)-free device
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- Preconditioning acc. to JEDEC level 2a
- ESD-withstand voltage: up to 2 kV according to JESD22-A114-B
- Qualified according Vishay automotive requirement



### APPLICATIONS

- Automotive: backlighting in dashboards and switches
- Telecommunication: indicator and backlighting in telephone and fax
- Indicator and backlight for audio and video equipment
- Indicator and backlight in office equipment
- Flat backlight for LCDs, switches and symbols
- General use

### PARTS TABLE

PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY
VLMK31P2S1-GS08	Red, $I_V = (56 \text{ to } 224) \text{ mcd}$	AllnGaP on GaAs
VLMK31P2S1-GS18	Red, $I_V = (56 \text{ to } 224) \text{ mcd}$	AllnGaP on GaAs
VLMK31Q1R2-GS08	Red, $I_V = (71 \text{ to } 180) \text{ mcd}$	AllnGaP on GaAs
VLMK31Q1R2-GS18	Red, $I_V = (71 \text{ to } 180) \text{ mcd}$	AllnGaP on GaAs
VLMK31R1S1-GS08	Red, $I_V = (112 \text{ to } 224) \text{ mcd}$	AllnGaP on GaAs
VLMK31R1S1-GS18	Red, $I_V = (112 \text{ to } 224) \text{ mcd}$	AllnGaP on GaAs
VLMK31R1S2-GS08	Red, $I_V = (112 \text{ to } 280) \text{ mcd}$	AllnGaP on GaAs
VLMK31R1S2-GS18	Red, $I_V = (112 \text{ to } 280) \text{ mcd}$	AllnGaP on GaAs
VLMK31R2S2-GS08	Red, $I_V = (140 \text{ to } 280) \text{ mcd}$	AllnGaP on GaAs
VLMK31R2S2-GS18	Red, $I_V = (140 \text{ to } 280) \text{ mcd}$	AllnGaP on GaAs



ABSOLUTE MAXIMUM RATINGS <sup>1)</sup> VLMK31..				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage <sup>2)</sup>		$V_R$	5	V
DC Forward current	$T_{amb} \leq 85 \text{ }^\circ\text{C}$	$I_F$	30	mA
Surge forward current	$t_p \leq 10 \text{ } \mu\text{s}$	$I_{FSM}$	0.1	A
Power dissipation		$P_V$	80	mW
Junction temperature		$T_j$	125	$^\circ\text{C}$
Operating temperature range		$T_{amb}$	- 40 to + 100	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	- 40 to + 100	$^\circ\text{C}$
Thermal resistance junction/ambient	Mounted on PC board (pad size > 16 mm <sup>2</sup> )	$R_{thJA}$	400	K/W

Note:

<sup>1)</sup>  $T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

<sup>2)</sup> Driving LED in reverse direction is suitable for short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS <sup>1)</sup> VLMK31..., RED							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity <sup>2)</sup>	$I_F = 20 \text{ mA}$	VLMK31P2S1	$I_V$	56		224	mcd
		VLMK31Q1R2	$I_V$	71		180	mcd
		VLMK31R1S1	$I_V$	112		224	mcd
		VLMK31R1S2	$I_V$	112		280	mcd
		VLMK31R2S2	$I_V$	140		280	mcd
Dominant wavelength	$I_F = 20 \text{ mA}$		$\lambda_d$		630		nm
Peak wavelength	$I_F = 20 \text{ mA}$		$\lambda_p$		643		nm
Angle of half intensity	$I_F = 20 \text{ mA}$		$\varphi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		1.9	2.6	V
Reverse voltage	$I_R = 10 \text{ } \mu\text{A}$		$V_R$	5			V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		15		pF

Note:

<sup>1)</sup>  $T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

<sup>2)</sup> In one packing unit  $I_{Vmax}/I_{Vmin} \leq 2.0$

LUMINOUS INTENSITY CLASSIFICATION				
GROUP	LIGHT INTENSITY (mcd)			
	STANDARD	OPTIONAL	MIN.	MAX.
P	1	45	56	
	2	56	71	
Q	1	71	90	
	2	90	112	
R	1	112	140	
	2	140	180	
S	1	180	224	
	2	224	280	

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of  $\pm 11 \%$ .

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.

In order to ensure availability, single wavelength groups will not be orderable.

CROSSING TABLE	
VISHAY	OSRAM
VLMK31P2S1	LST676-P2S1
VLMK31Q1R2	LST676-Q1R2
VLMK31R1S1	LST676-R1S1
VLMK31R1S2	LST676-R1S2
VLMK31R2S2	LST676-R2S2

**TYPICAL CHARACTERISTICS**

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

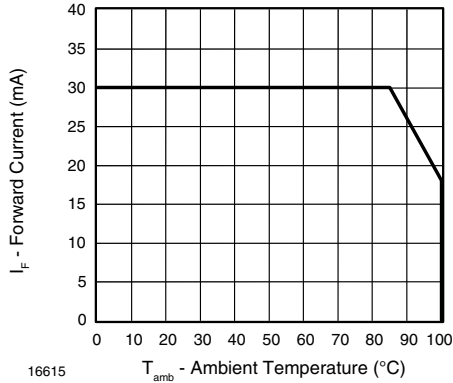


Figure 1. Max. Permissible Forward Current vs. Ambient Temperature

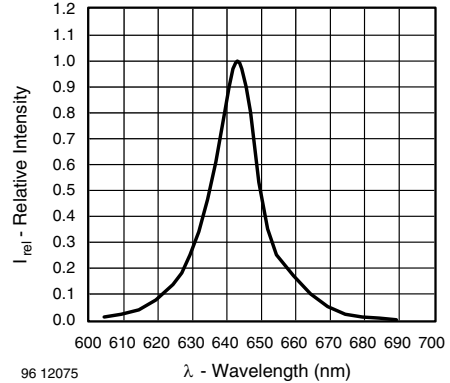


Figure 4. Relative Intensity vs. Wavelength

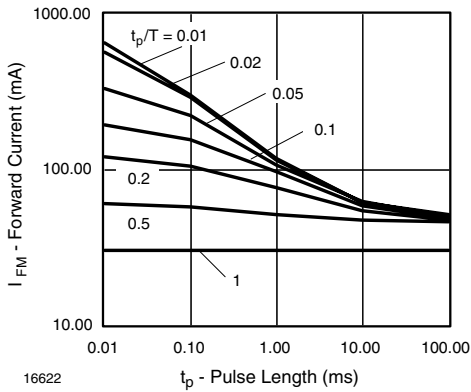


Figure 2. Permissible Forward Current vs. Pulse Length

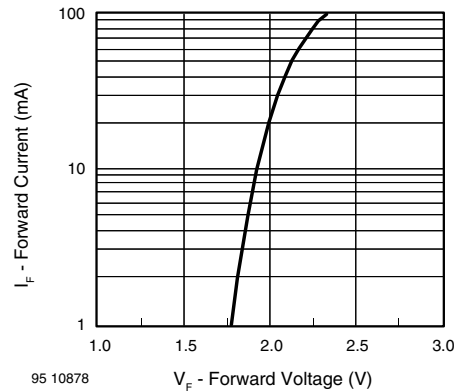


Figure 5. Forward Current vs. Forward Voltage

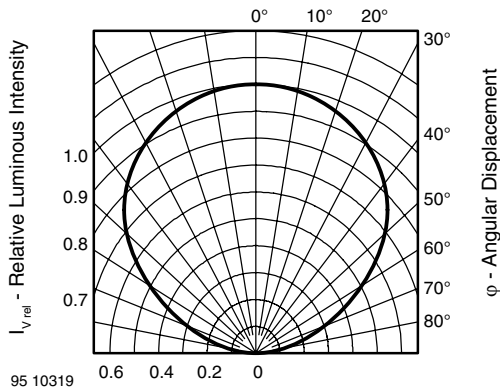


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

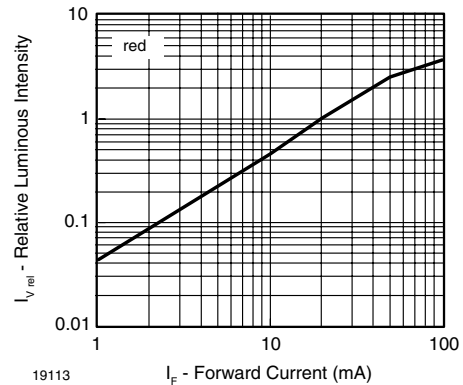


Figure 6. Relative Luminous Intensity vs. Forward Current

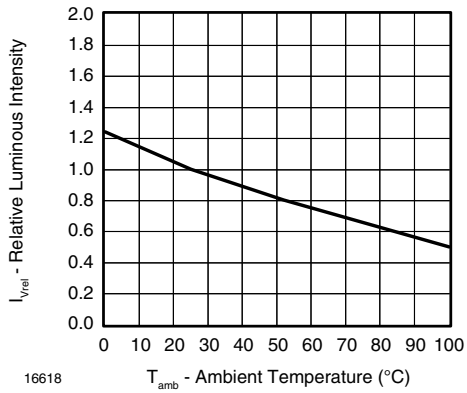


Figure 7. Rel. Luminous Intensity vs. Ambient Temperature

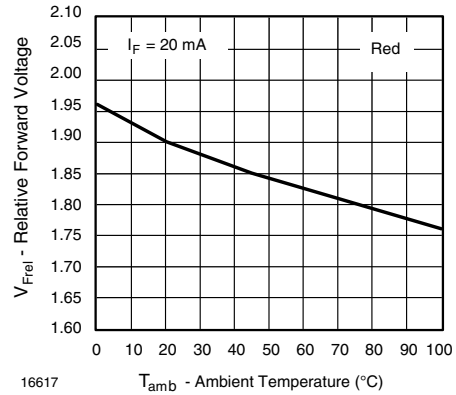
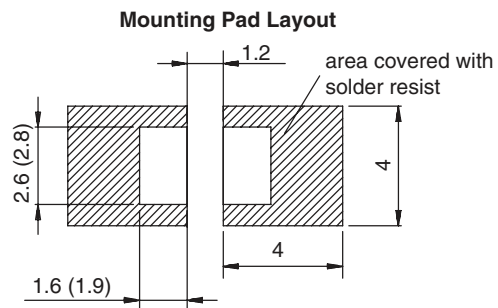
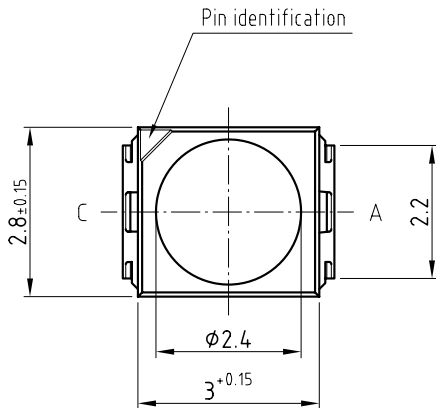
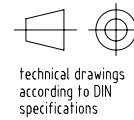
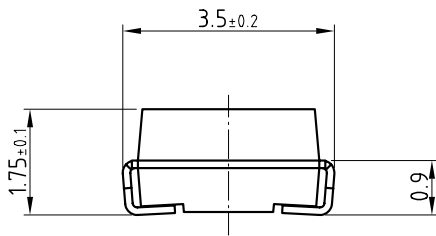


Figure 8. Forward Voltage vs. Ambient Temperature

**PACKAGE DIMENSIONS** in millimeters

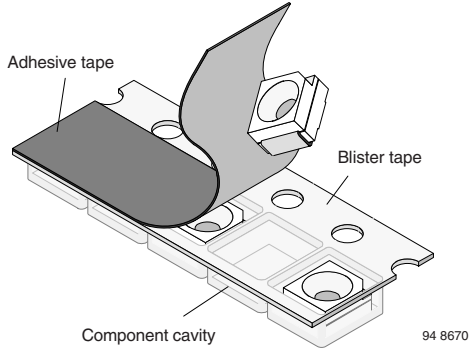


Drawing-No.: 6.541-5067.01-4  
 Issue: 4; 30.07.07  
 20541

**METHOD OF TAPING/POLARITY AND TAPE AND REEL**

**SMD LED (VLM3-SERIES)**

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



**REEL PACKAGE DIMENSION IN MM FOR SMD LED, TAPE OPTION GS18 (= 8000 PCS.) PREFERRED**

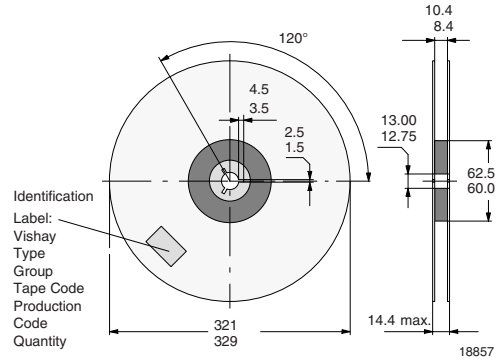


Figure 11. Reel Dimensions - GS18

**TAPING OF VLM.3..**

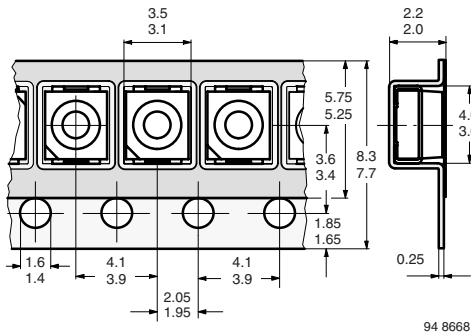


Figure 9. Tape Dimensions in mm for PLCC-2

**SOLDERING PROFILE**

IR Reflow Soldering Profile for Lead (Pb)-free Soldering  
Preconditioning acc. to JEDEC Level 2a

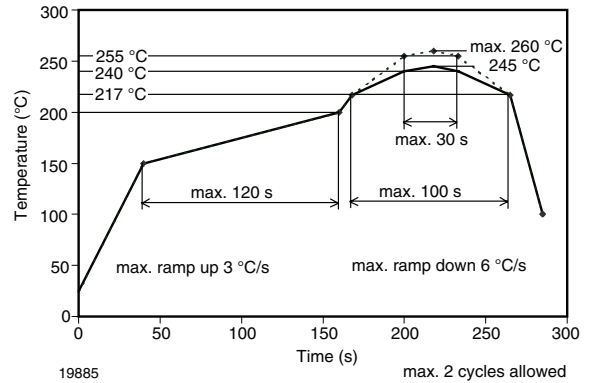


Figure 12. Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020C)

**REEL PACKAGE DIMENSION IN MM FOR SMD LED, TAPE OPTION GS08 (= 1500 PCS.)**

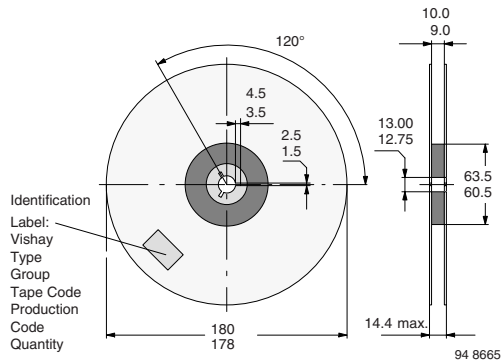


Figure 10. Reel Dimensions - GS08

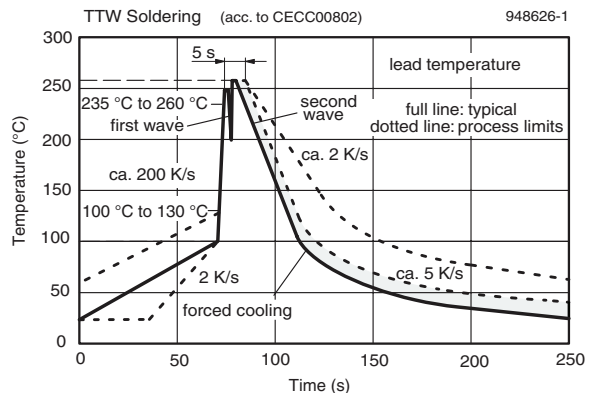
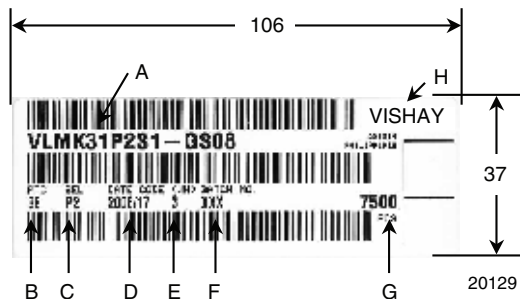


Figure 13. Double Wave Soldering of Opto Devices (all Packages)

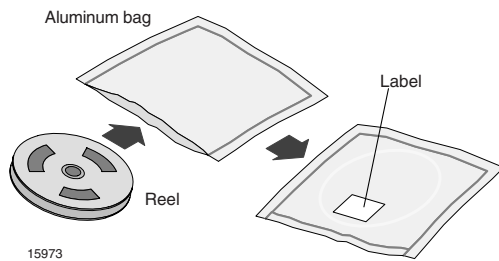
**BAR CODE PRODUCT LABEL  
EXAMPLE:**



- A) Type of component
- B) Manufacturing plant
- C) SEL - selection code (bin):  
e.g.: P2 = code for luminous intensity group
- D) Date code year/week
- E) Day code (e.g. 3: Wednesday)
- F) Batch no.
- G) Total quantity
- H) Company code

**DRY PACKING**

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



**FINAL PACKING**

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

**RECOMMENDED METHOD OF STORAGE**

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

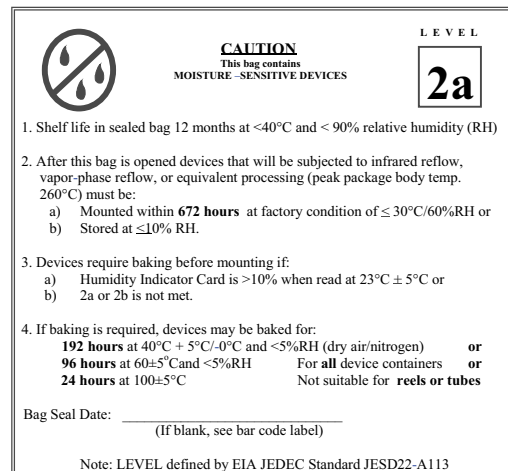
- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

- 192 h at 40 °C + 5 °C/ - 0 °C and < 5 % RH (dry air/nitrogen) or
- 96 h at 60 °C + 5 °C and < 5 % RH for all device containers or
- 24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

**ESD PRECAUTION**

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

**VISHAY SEMICONDUCTORS STANDARD  
BAR CODE LABELS**

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.

**OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.